

HD74HC152

1-of-8-line Data Selector/Multiplexer

HITACHI

Description

This data selector/multiplexer contains full-on-chip binary decoding to select the desired data source. The HD74HC152 selects one-of-eight data sources.

Features

- High Speed Operation: t_{pd} (Any D to W) = 17 ns typ ($C_L = 50$ pF)
- High Output Current: Fanout of 10 LSTTL Loads
- Wide Operating Voltage: $V_{CC} = 2$ to 6 V
- Low Input Current: 1 μ A max
- Low Quiescent Supply Current: I_{CC} (static) = 4 μ A max ($T_a = 25^\circ\text{C}$)

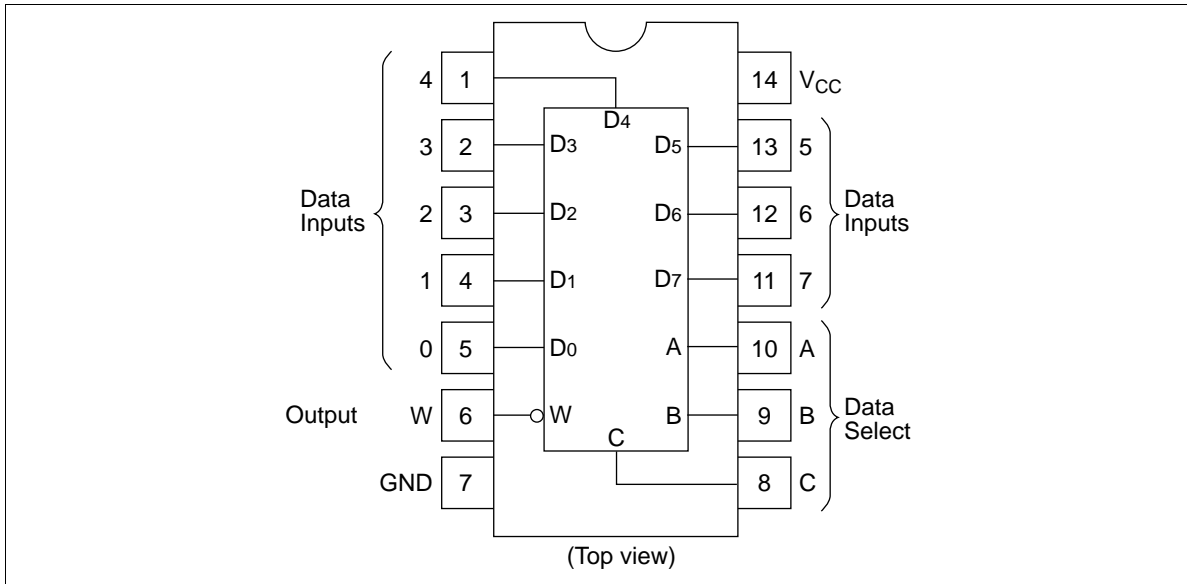
Function Table

Select inputs			Output	Select inputs			Output
C	B	A	W	C	B	A	W
L	L	L	\bar{D}_0	H	L	L	\bar{D}_4
L	L	H	\bar{D}_1	H	L	H	\bar{D}_5
L	H	L	\bar{D}_2	H	H	L	\bar{D}_6
L	H	H	\bar{D}_3	H	H	H	\bar{D}_7

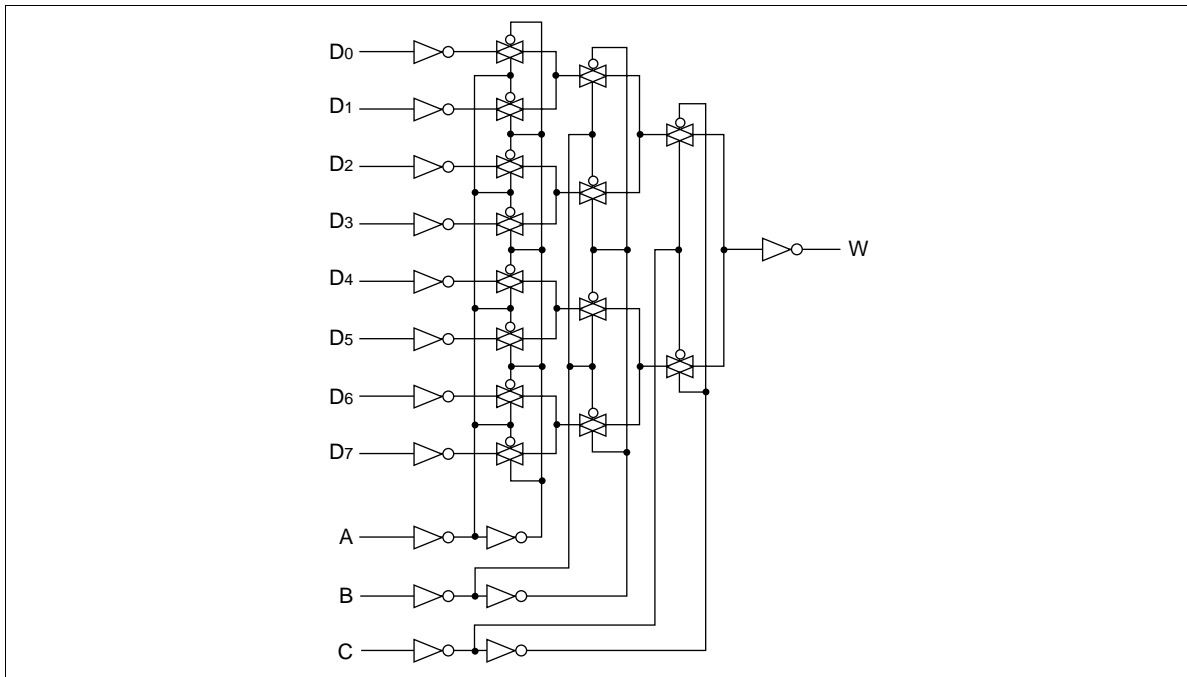
Note: \bar{D}_0 to \bar{D}_7 : the level of the D respective input

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Pin Arrangement



Logic Diagram



DC Characteristics

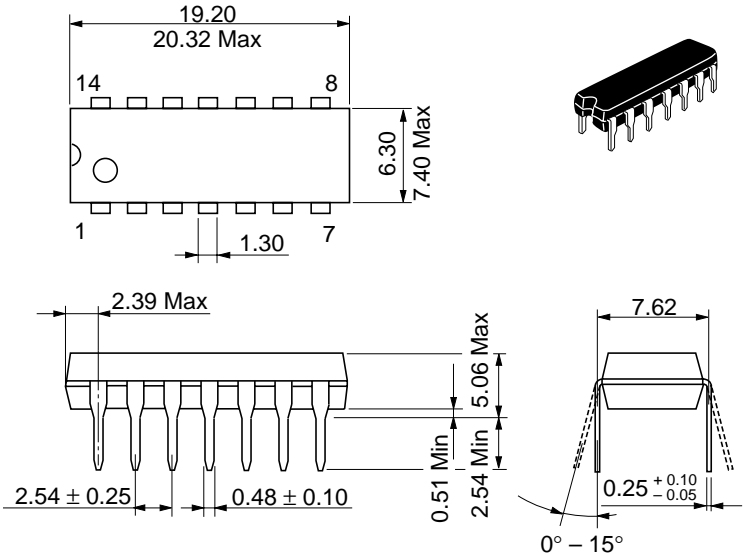
Item	Symbol	V _{CC} (V)	Ta = 25°C			Ta = -40 to +85°C		Unit	Test Conditions	
			Min	Typ	Max	Min	Max			
Input voltage	V _{IH}	2.0	1.5	—	—	1.5	—	V		
		4.5	3.15	—	—	3.15	—			
		6.0	4.2	—	—	4.2	—			
	V _{IL}	2.0	—	—	0.5	—	0.5			V
		4.5	—	—	1.35	—	1.35			
		6.0	—	—	1.8	—	1.8			
Output voltage	V _{OH}	2.0	1.9	2.0	—	1.9	—	V	Vin = V _{IH} or V _{IL} I _{OH} = -20 μA	
		4.5	4.4	4.5	—	4.4	—			
		6.0	5.9	6.0	—	5.9	—			
		4.5	4.18	—	—	4.13	—			I _{OH} = -4 mA
		6.0	5.68	—	—	5.63	—			I _{OH} = -5.2 mA
	V _{OL}	2.0	—	0.0	0.1	—	0.1	V	Vin = V _{IH} or V _{IL} I _{OL} = 20 μA	
		4.5	—	0.0	0.1	—	0.1			
		6.0	—	0.0	0.1	—	0.1			
		4.5	—	—	0.26	—	0.33			I _{OL} = 4 mA
		6.0	—	—	0.26	—	0.33			I _{OL} = 5.2 mA
Input current	I _{in}	6.0	—	—	±0.1	—	±1.0	μA	Vin = V _{CC} or GND	
Quiescent supply current	I _{CC}	6.0	—	—	4.0	—	40	μA	Vin = V _{CC} or GND, I _{out} = 0 μA	

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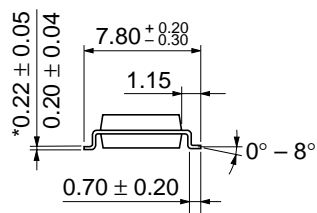
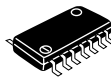
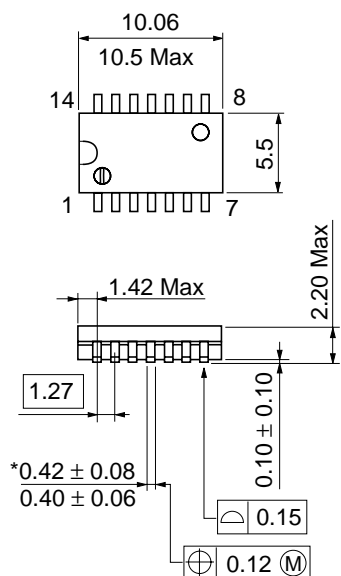
AC Characteristics ($C_L = 50$ pF, Input $t_r = t_f = 6$ ns)

Item	Symbol	V_{CC} (V)	Ta = 25°C		Ta = -40 to +85°C		Unit	Test Conditions		
			Min	Typ	Max	Min			Max	
Propagation delay time	t_{PLH}	2.0	—	—	160	—	200	ns	A, B or C to W	
	t_{PHL}	4.5	—	17	32	—	40			
		6.0	—	—	27	—	34			
			2.0	—	—	150	—	190	ns	Any D to W
			4.5	—	15	30	—	38		
			6.0	—	—	26	—	33		
Output rise/fall time	t_{TLH}	2.0	—	—	75	—	95	ns		
	t_{THL}	4.5	—	5	15	—	19			
		6.0	—	—	13	—	16			
Input capacitance	C_{in}	—	—	5	10	—	10	pF		

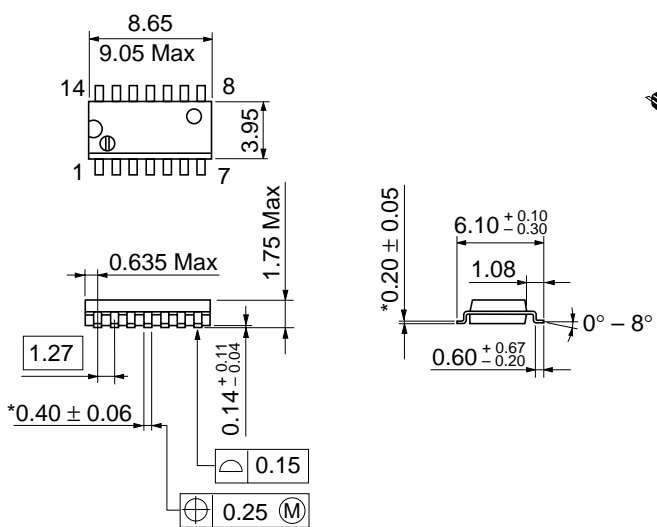
Unit: mm



Unit: mm



Unit: mm



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